

Inventor(s): MIYASHITA et al.

Appl. No.: 09 916,530

Series Code ↑ Serial No. ↑

Filed: July 30, 2001

Hon. Commissioner of Patents  
Washington, D.C. 20231

Sir:

**REPLY/AMENDMENT/LETTER**

Date: February 20, 2003

Group Art Unit 2812  
 Examiner: Ron Everett Pompey  
 Atty. Dkt. P 279038 T1HM-98S0740-D  
 M# Client Ref

Appl. Title: Semiconductor device comprising metal  
 silicide films formed to cover gate  
 electrode and source-drain diffusion  
 layers and method of manufacturing the  
 same

This is a reply/amendment/letter in the above-identified application and includes the herewith attachment of same date and subject which is incorporated hereinto by reference and the signature below is treated as the signature to the attachment in absence of a signature thereto.

**FEE REQUIREMENTS FOR CLAIMS AS AMENDED**

## 1. Small Entity claim

- A. ☒ NOT made  
 B. ☐ Withdrawn  
 C. ☐ made herewith  
 D. ☐ made previously
- For B & C  
 See **Required  
 Separate Paper  
 (Pat-256)**

Claims remaining after amendment	Highest number previously paid for	Present Extra	Large/Small Entity	Additional Fee	Fee Code Lg/Sm
2. Total Effective Claims	2	**minus 20 0	x \$18/\$9 =	+ \$0	103/203
3. Independent Claims	1	***minus 3 0	x \$84/\$42 =	+ \$0	102/202
4. If amendment enters proper multiple dependent claim(s) into this application for first time (leave blank if this is a reissue application) .....			add	+ \$280/\$140 =	+ \$0 104/204
5. Original due Date: February 20, 2003			<input type="checkbox"/> NONE		
6. Petition is hereby made to extend the original due date to cover the date this response is filed for which the requisite fee is attached			(1 mo) \$110/\$55 = (2 mos) \$400/\$200 = (3 mos) \$920/\$460 = (4 mos) \$1,440/\$720 = (5 mos) \$1,960/\$980 =	+ \$0	115/215 116/216 117/217 118/218 128/228
7. Enter any previous extension fee paid since above original due date and subtract			- \$0		
8.			Extension Fee	+ \$0	
9. If Terminal Disclaimer attached, add Rule 20(d) official fee .....			+ \$110/\$55	+ \$0	148/248
10. If IDS attached requires Official Fee under Rule 97 (c), .....			add + \$180	+ \$0	126
or if Rule 97(d) Request .....			add + \$180		126
11. After-Final Request Fee per rules 129(a) and 17(r) .....			+ \$740/370	+ \$0	146/246
12. No. of additional inventions for examination per Rule 129(b).....			x \$740/370 ea	+ \$0	149/249
13. Request for Continued Examination (RCE) .....			+ \$740/370	+ \$0	1179/1279
14. Petition fee for .....				+ \$0	
15.			TOTAL FEE =	\$0	
16. *If the entry in this space is less than entry in next space, the "Present Extra" result is "0".					
17. **If the "Highest number previously paid for" in this space is less than 20, write "20" in this space.					
18. ***If the "Highest number previously paid for" in this space is less than 3, write "3" in this space.					

**PLEASE CHARGE  
 OUR DEP. ACCT**

Our Deposit Account No. 03-3975)

(Our Order No. 8312 279038

C#

M#

**CHARGE STATEMENT:** The Commissioner is hereby authorized to charge any fee specifically authorized hereafter, or any missing or insufficient fee(s) filed, or asserted to be filed, or which should have been filed herewith or concerning any paper filed hereafter, and which may be required under Rules 16-18 (missing or insufficiencies only) now or hereafter relative to this application and the resulting Official Document under Rule 20, or credit any overpayment, to our Accounting/Order Nos. shown above, for which purpose a duplicate copy of this sheet is attached.

This CHARGE STATEMENT **does not authorize** charge of the **issue fee** until/unless an issue fee transmittal sheet is filed.

Query: Is appeal deadline now? If  
 so, file Notice of Appeals separately.

Pillsbury Winthrop LLP  
 Intellectual Property Group

By Atty: Glenn J. Perry

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Sig: *[Signature]* 39328

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Atty/Sec: gjp/ml

**NOTE: File this cover sheet in duplicate with PTO receipt (PAT-103A) and attachments**



# 10/B

3/3/03  
Muni=h

In re PATENT APPLICATION OF

Confirmation No.: 9248

MIYASHITA et al.

Group Art Unit: 2812

Appln. No.: 09/916,530

Examiner: Ron Everett Pompey

Filed: July 30, 2001

Title: Semiconductor device comprising metal silicide films formed to cover gate electrode and source-drain diffusion layers and method of manufacturing the same

February 20, 2003

\* \* \* \* \*

**RESPONSE TO OFFICE ACTION**

Hon. Commissioner of Patents  
Washington, D.C. 20231

Sir:

In response to the Official Action dated November 20, 2002, please amend this application as set forth herein. This Amendment is intended to comply with the new format promulgated by the USPTO in February, 2003.

RECEIVED  
FEB 24 2003  
TECHNOLOGY CENTER 2800